

## Super Barrier Rectifier ™

Using state-of-the-art SBR IC process technology, the following features are made possible in a single device:

## Major ratings and characteristics

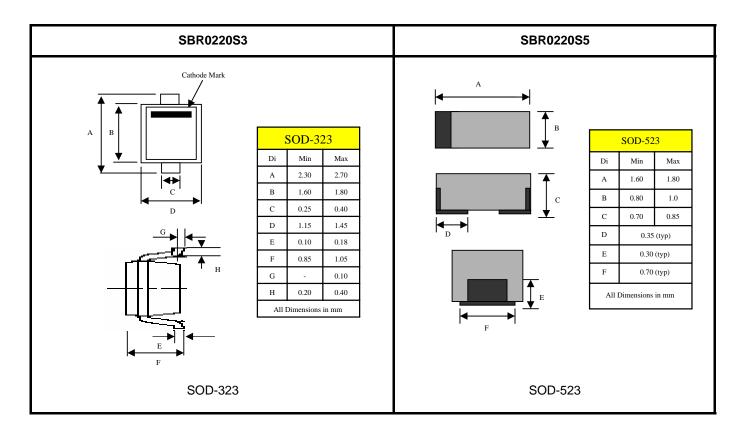
Characteristics	Values	Units
I <sub>F(AV)</sub> Rectangular Waveform	0.2	Α
$V_{RRM}$	20	V
V <sub>F</sub> @0.2A, T <sub>J</sub> =75°C	0.43	V, typ
T <sub>J</sub> (operating/storage)	-65 to 125	°C

## **ELECTRICAL:**

- \* Low Forward Voltage Drop
- \* Low Reverse Leakage
- \* Reliable High Temperature Operation
- \* Super Barrier Design
- \* Softest, fast switching capability
- \* 125°C Operating Junction Temperature

## MECHANICAL:

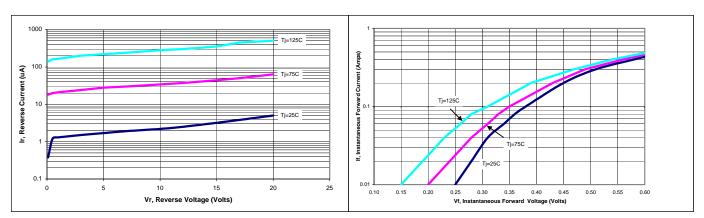
\* Molded Plastic SOD-323, SOD-523 packages



	SYMBOL			UNITS
DC Blocking Voltage Working Peak Reverse Voltage Peak Repetitive Reverse Voltage	V <sub>RM</sub> V <sub>RWM</sub> V <sub>RRM</sub>	20		Volts
Average Rectified Forward Current (Rated V <sub>R</sub> -20Khz Square Wave)-50% duty cycle	Io	0.2		Amps
Peak Forward Surge Current - 1/2 60hz	I <sub>FSM</sub>	2		Amps
Instantaneous Forward Voltage $I_F = 200 \text{mA}$ ; $T_J = 25^{\circ}\text{C}$ $I_F = 200 \text{mA}$ ; $T_J = 75^{\circ}\text{C}$	V <sub>F</sub>	Тур  	Max 0.49 0.47	Volts
Maximum Reverse Current at Rated $V_{RM}$ $T_J = 25^{\circ}C$ $T_J = 75^{\circ}C$	I <sub>R</sub> *	Typ  	Max 20 500	uA uA
Operating and Storage Junction Temperature	TJ	-65 to +125		°C

NOTE: Dice are available for customer applications.

<sup>\*</sup> Pulse width < 300 uS, Duty cycle < 2%



**Figure 1: Typical Reverse Current** 

Figure 2: Typical Forward Voltage

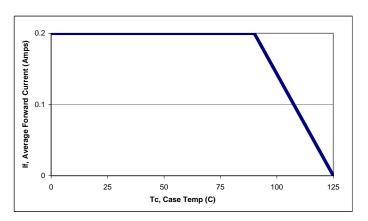


Figure 3: Current Derating, Case

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▲APD Semiconductor, Inc.

1 Lagoon Drive, Suite 410, Redwood City, CA 94065, USA Ph: 650 508 8896 FAX: 650 508 8865 Homepage: www.apdsemi.com email: info@apdsemi.com